

## X3-Class HiPERFET™ **Power MOSFET**

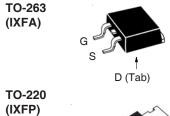
# **IXFA50N20X3** IXFP50N20X3

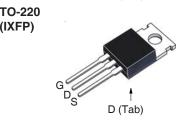
= 200V50A  $30m\Omega$ 

N-Channel Enhancement Mode Avalanche Rated



G
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G = Gate	D	=	Drain
S = Source	Tab	=	Drain

Symbol	Test Conditions	Maximum R	atings
V <sub>DSS</sub>	$T_{_{\rm J}}$ = 25°C to 150°C	200	V
V <sub>DGR</sub>	$T_J = 25^{\circ}C$ to 150°C, $R_{GS} = 1M\Omega$	200	V
V <sub>GSS</sub>	Continuous	±20	V
V <sub>GSM</sub>	Transient	±30	V
I <sub>D25</sub>	T <sub>C</sub> = 25°C	50	A
I <sub>DM</sub>	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	70	Α
I <sub>A</sub>	T <sub>C</sub> = 25°C	25	А
E <sub>AS</sub>	$T_{c} = 25^{\circ}C$	400	mJ
dv/dt	$I_{S} \leq I_{DM}, V_{DD} \leq V_{DSS}, T_{J} \leq 150^{\circ}C$	50	V/ns
$\overline{P_{D}}$	T <sub>C</sub> = 25°C	240	W
T <sub>J</sub>		-55 +150	°C
T <sub>JM</sub>		150	°C
T <sub>stg</sub>		-55 +150	°C
T <sub>L</sub>	Maximum Lead Temperature for Soldering	g 300	°C
T <sub>SOLD</sub>	1.6 mm (0.062in.) from Case for 10s	260	°C
F <sub>c</sub>	Mounting Force (TO-263) Mounting Torque (TO-220)	1065 / 2.214.6 1.13 / 10	N/lb Nm/lb.in
Weight	TO-263 TO-220	2.5 3.0	g g

### **Features**

- International Standard Packages
- Low R<sub>DS(ON)</sub> and Q<sub>G</sub>
   Avalanche Rated
- Low Package Inductance

#### **Advantages**

- High Power Density
- Easy to Mount
- Space Savings

#### **Applications**

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

Symbol (T <sub>J</sub> = 25°C,	<b>Test Conditions</b> Unless Otherwise Specified)	Chara Min.	cteristic Typ.	Values Max.
BV <sub>DSS</sub>	$V_{GS} = 0V, I_D = 1mA$	200		V
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_{D} = 1 \text{mA}$	2.5		4.5 V
I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100 nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}$ , $V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			10 μA 350 μA
R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$		25	30 mΩ



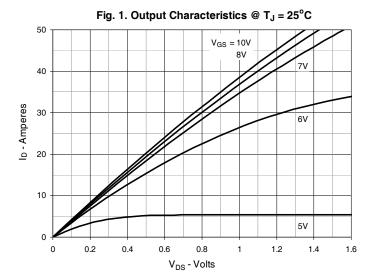
Symbol	Test Conditions	Characteristic Values		<b>Values</b>
$(T_J = 25^{\circ}C,$	Unless Otherwise Specified)	Min.	Тур.	Max
g <sub>fs</sub>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.5 • I <sub>D25</sub> , Note 1	25	42	S
$R_{Gi}$	Gate Input Resistance		1.9	Ω
C <sub>iss</sub>			2100	pF
C <sub>oss</sub>	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		390	pF
C <sub>rss</sub>			1.5	pF
	Effective Output Capacitance			
$C_{o(er)}$	Energy related $\int V_{GS} = 0V$		200	pF
$C_{o(tr)}$	Time related $\int_{DS} V_{DS}^{GS} = 0.8 \cdot V_{DSS}$		600	pF
t <sub>d(on)</sub>	Resistive Switching Times		16	ns
t <sub>r</sub>	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		24	ns
t <sub>d(off)</sub>	$R_{G} = 100$ , $V_{DS} = 0.0$ $V_{DSS}$ , $I_{D} = 0.0$ $I_{D25}$		46	ns
t,	n <sub>G</sub> = 1052 (External)		11	ns
Q <sub>g(on)</sub>			33	nC
Q <sub>gs</sub>	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		8	nC
Q <sub>gd</sub>			10	nC
R <sub>thJC</sub>				0.52 °C/W
R <sub>thCS</sub>	TO-220		0.50	°C/W

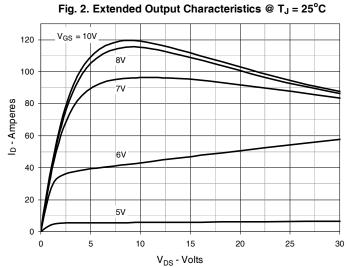
#### Source-Drain Diode

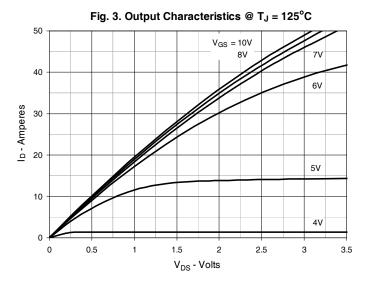
Symbol $(T_J = 25^{\circ}C, U)$	Test Conditions Unless Otherwise Specified)	Chara Min.	cteristic Typ.	Values Max	
I <sub>s</sub>	$V_{GS} = 0V$			50	Α
I <sub>SM</sub>	Repetitive, Pulse Width Limited by $T_{_{JM}}$			200	Α
V <sub>SD</sub>	$I_F = I_S$ , $V_{GS} = 0V$ , Note 1			1.4	V
$\left. egin{array}{c} \mathbf{t}_{rr} & \\ \mathbf{Q}_{RM} & \\ \mathbf{I}_{RM} & \end{array}  ight.  ight.$	$I_F = 25A$ , -di/dt = 100A/ $\mu$ s $V_R = 100V$		70 220 6.2		ns nC A

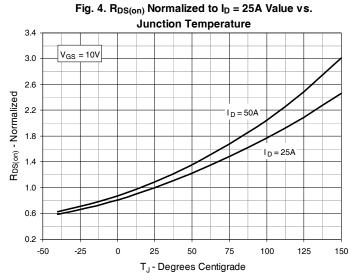
Note 1. Pulse test,  $t \le 300\mu s$ , duty cycle,  $d \le 2\%$ .

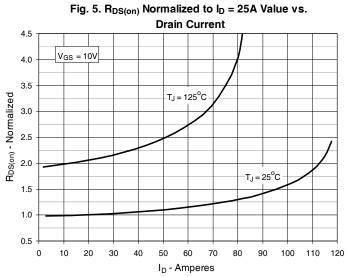


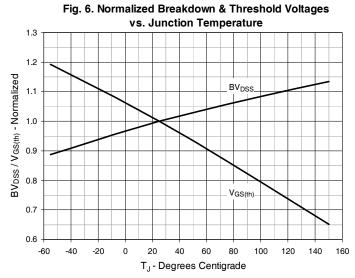




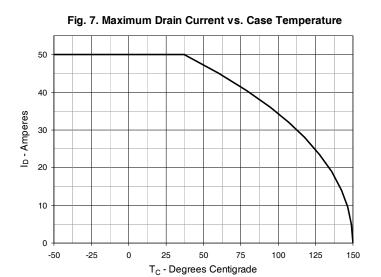


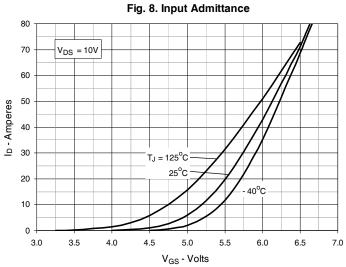


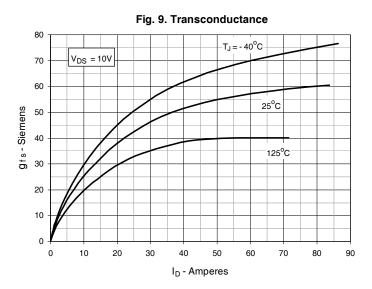


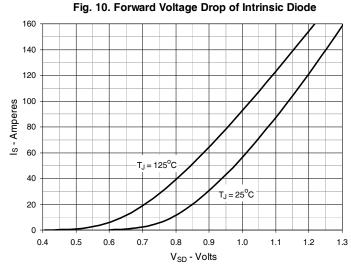


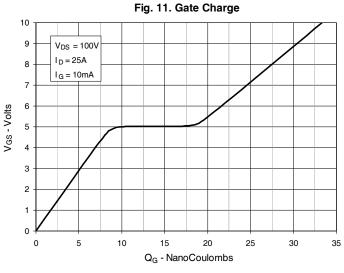


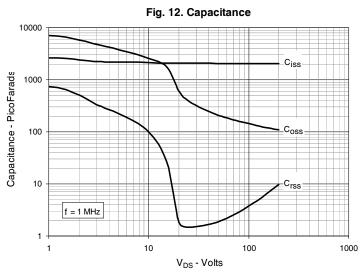






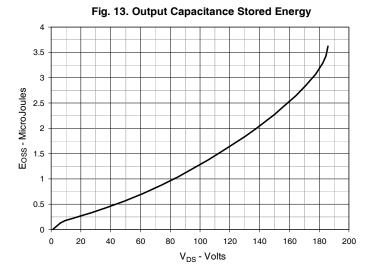






IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.





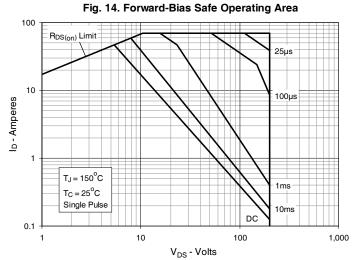
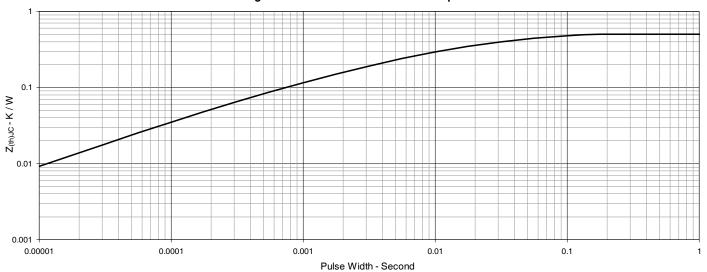
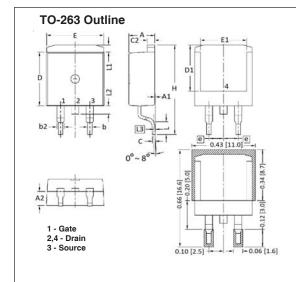


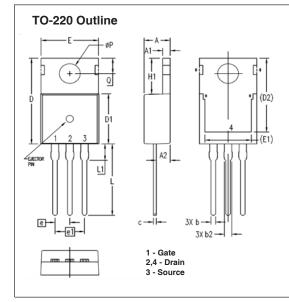
Fig. 15. Maximum Transient Thermal Impedance







SYM	INCHES		MILLIMETER		
21M	MIN	MAX	MIN	MAX	
Α	.170	.185	4.30	4.70	
A1	.000	.008	0.00	0.20	
A2	.091	.098	2.30	2.50	
Ь	.028	.035	0.70	0.90	
b2	.046	.060	1.18	1.52	
С	.018	.024	0.45	0.60	
C2	.049	.060	1.25	1.52	
D	.340	.370	8.63	9.40	
D1	.300	.327	7.62	8.30	
E	.380	.410	9.65	10.41	
E1	.270	.330	6.86	8.38	
е	.100	BSC	2.54	BSC	
Н	.580	.620	14.73	15.75	
L	.075	.105	1.91	2.67	
L1	.039	.060	1.00	1.52	
L2	_	.070	_	1.77	
L3	.010	BSC	0.254	BSC	



SYM	INC	INCHES		ETERS
2114	MIN	MAX	MIN	MAX
Α	.169	.185	4.30	4.70
A1	.047	.055	1.20	1.40
A2	.079	.106	2.00	2.70
Ф	.024	.039	0.60	1.00
b2	.045	.057	1.15	1.45
O	.014	.026	0.35	0.65
	.587	.626	14.90	15.90
D1	.335	.370	8.50	9.40
(D2)	.500	.531	12.70	13.50
E	.382	.406	9.70	10.30
(E1)	.283	.323	7.20	8.20
ψ	.100 BSC		2.54 BSC	
e1	.200 BSC		5.08 BSC	
H1	.244	.268	6.20	6.80
L	.492	.547	12.50	13.90
L1	.110	.154	2.80	3.90
ØΡ	.134	.150	3. <b>4</b> 0	3.80
Q	.106	.126	2.70	3.20





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